Docket No.: M4065.0278/P278

(PATENT)

JAN 2 3 2002

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Kevin L. Beaman, et al.

Application No.: 09/653,281

Filed: August 31, 2000

For: USE OF ATOMIC OXIDATION FOR

FABRICATING OF OXIDE-NITRIDE-OXIDE STACK FOR FLASH MEMORY

DEVICES

Group Art Unit: 2815

Examiner: J. Nguyen

TO 28 ON THE CELL BOOK

AMENDMENT

Box Non-Fee Amendment

Commissioner for Patents Washington, DC 20231

Dear Sir:

In response to the Office Action dated November 1, 2001 (Paper No. 7), please amend the above-identified U.S. Patent application as follows:

In the Claims:

Please rewrite claims 5, 20 and 35 as shown in the Replacement Claims:

1367339 v1; TB1N01!.DOC